



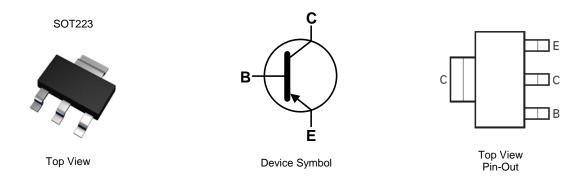
# Features

- BV<sub>CEO</sub> > -140V
- I<sub>C</sub> = -4A High Continuous Collector Current
- I<sub>CM</sub> = -10A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -150mV @ -1A</li>
- hFE Specified up to -10A for a High Gain Hold-up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### 140V PNP MEDIUM POWER TRANSISTOR IN SOT223

#### **Mechanical Data**

- Case: SOT223
- Case material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



#### Ordering Information (Notes 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT955TA	FZT955	7	12	1,000

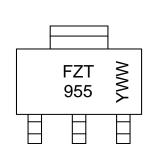
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



SOT223

FZT 955 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{W}W$  = Week Code (01~53)



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-180	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-140	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	lc	-4	А
Peak Pulse Current	I <sub>CM</sub>	-10	А

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	6	3.0 24	W mW /°C	
Linear Derating Factor	(Note 6)	P <sub>D</sub>	1.6 12.8		
Thermal Desistance, Junction to Ambient	(Note 5)	R <sub>θ</sub> JA	42		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	78	°C/W	
Thermal Resistance Junction to Lead	(Note 7)	R <sub>θJL</sub>	8.84		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

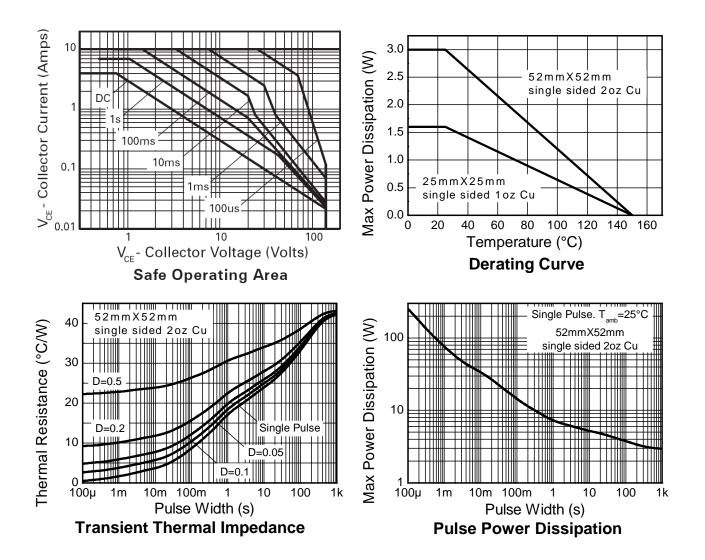
### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air For a device mounted with the collector lead on 52mm x 52mm x 52mm 202 copper that is conditions whilst operating in steady-state.
Same as Note 5, except the device is mounted on 25mm x 25mm 10z copper.
Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



### Thermal Characteristics and Derating Information





# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

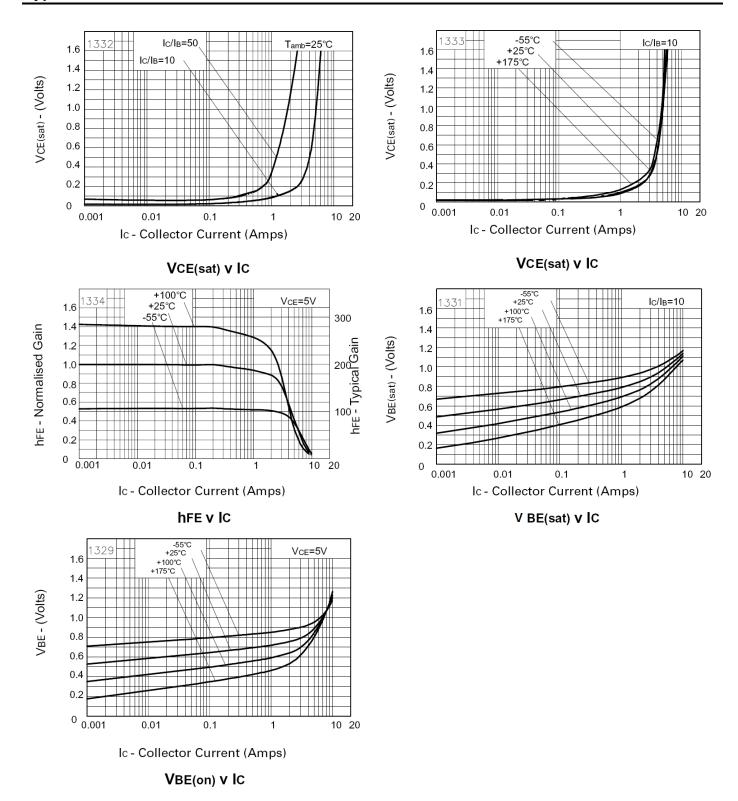
			Y.			
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-180	-210	-	V	$I_{\rm C} = -100 \mu {\rm A}$
Collector-Emitter Breakdown Voltage	BV <sub>CER</sub>	-180	-210	-	V	$I_C = -1\mu A$ , $R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-140	-170	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8	-	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current	I	-	<1	-50	nA	V <sub>CB</sub> = -150V
	I <sub>CBO</sub>	-	-	-1	μA	V <sub>CB</sub> = -150V, T <sub>A</sub> = +100°C
Collector Cut-Off Current	ICER	-	<1	-50	nA	V <sub>CE</sub> = -150V
	R ≤1kΩ	-	-	-1	μA	$V_{CE} = -150V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I <sub>EBO</sub>	-	-	-10	nA	$V_{EB} = -6V$
		100	200	-	-	$I_{C} = -10mA, V_{CE} = -5V$
DC Current Transfer Static Ratio (Note 9)	L.	100	200	300		$I_{C} = -1A, V_{CE} = -5V$
	h <sub>FE</sub>	75	140	-		I <sub>C</sub> = -3A, V <sub>CE</sub> = -5V
		-	10	-		I <sub>C</sub> = -10A, V <sub>CE</sub> = -5V
		-	-30	-60	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -5mA
Collector Emitter Coturation Makers (Nate O)	V <sub>CE(sat)</sub>	-	-70	-120		I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Collector-Emitter Saturation Voltage (Note 9)		-	-110	-150		I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
		-	-275	-370		$I_{\rm C} = -3A, I_{\rm B} = -300 {\rm mA}$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	-970	-1,110	mV	I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	-	-830	-950	mV	I <sub>C</sub> = -3A, V <sub>CE</sub> = -5V
Transitional Frequency (Note 9)	f⊤	-	110	-	MHz	$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V}, $ f = 50MHz
Output Capacitance	Cobo	-	40	-	pF	V <sub>CB</sub> = -20V, f = 1MHz
Switching Time	t <sub>ON</sub>	-	68	-	20	$V_{CC} = -50V, I_C = -1A,$
Switching Time	tOFF	-	1,030	-	ns	$-I_{B1} = I_{B2} = -100 \text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# **FZT955**

# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

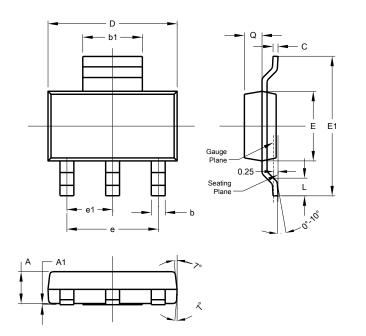




FZT955

# **Package Outline Dimensions**

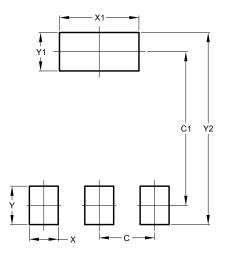
Please see http://www.diodes.com/package-outlines.html for the latest version.



-					
SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
E	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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